



2823

Atty. Docket No. 8017-1041

PATENTS

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of

Eiji HASEGAWA

Confirmation No. 1068

Serial No. 09/883,373

GROUP 2823

Filed June 19, 2001

Examiner Neal Berezny

SEMICONDUCTOR DEVICE HAVING A  
PLURALITY OF GATE INSULATING FILMS  
OF DIFFERENT THICKNESSES, AND METHOD  
OF MANUFACTURING SUCH SEMICONDUCTOR  
DEVICE

RECEIVED  
FEB - 6 2003  
TECHNICAL CENTER 2800  
2/11/03  
H10/B  
Adm H

AMENDMENT

Commissioner for Patents

Washington, D.C. 20231

Sir:

Responsive to the Official Action of November 20, 2002,  
please amend the above-identified application as follows:

IN THE TITLE:

Change the title throughout, declaration excepted, to  
--METHOD OF MANUFACTURING A SEMICONDUCTOR DEVICE HAVING A  
PLURALITY OF GATE INSULATING FILMS OF DIFFERENT THICKNESSES--.

IN THE CLAIMS:

Amend claim 1 as follows:

--1. (amended) A method of manufacturing a  
semiconductor device having a plurality of gate insulating films  
of different thicknesses on a semiconductor substrate, comprising  
the steps of:

13